

FB40 - FB380/C 1000G

FAST RECOVERY GLASS PASSIVATED BRIDGE RECTIFIERS

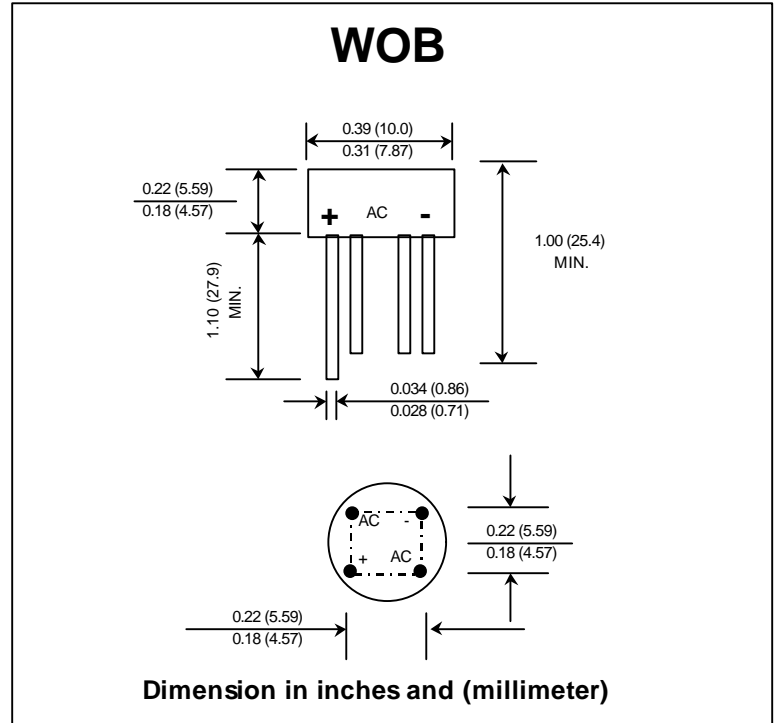
PRV : 100 - 900 Volts
Io : 1.0 Amperes

FEATURES :

- * Glass passivated chip
- * High case dielectric strength
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * Fast switching for high efficiency
- * Ideal for printed circuit board

MECHANICAL DATA :

- * Case : Reliable low cost construction utilizing molded plastic technique
- * Epoxy : UL94V-O rate flame retardant
- * Terminals : Plated leads solderable per MIL-STD-202, Method 208 guaranteed
- * Polarity : Polarity symbols marked on case
- * Mounting position : Any
- * Weight : 1.29 grams



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

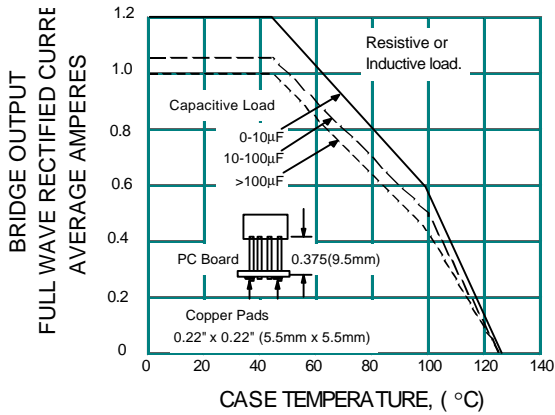
Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

| RATING | SYMBOL | FB40-C 1000G | FB80-C 1000G | FB125-C 1000G | FB250-C 1000G | FB380-C 1000G | UNIT |
|--|-----------------|-----------------|-----------------|------------------|------------------|------------------|--------------------|
| Maximum Recurrent Peak Reverse Voltage | V_{RRM} | 100 | 200 | 300 | 600 | 900 | Volts |
| Maximum RMS Input Voltage R+C -Load | V_{RMS} | 40 | 80 | 125 | 250 | 380 | Volts |
| Maximum DC Blocking Voltage | V_{DC} | 100 | 200 | 300 | 600 | 900 | Volts |
| Maximum Average Forward Current For Free Air Operation at $T_c = 45^\circ\text{C}$ R+L -Load C-Load | $I_{F(AV)}$ | 1.2 1.0 | | | | | Amps. |
| Peak Forward Surge Current Single half sine wave on rated load (JEDEC Method) at $T_J = 125^\circ\text{C}$ | I_{FSM} | 30 | | | | | Amps. |
| Rating for fusing at $T_J = 125^\circ\text{C}$ ($t < 100$ ms.) | I^2t | 10 | | | | | A ² S |
| Maximum Series Resistor C-Load $V_{RMS} = \pm 10\%$ | R_t | 1.0 | 2.0 | 4.0 | 8.0 | 12.0 | Ω |
| Maximum load Capacitance +50% -10% | C_L | 5000 | 2500 | 1000 | 500 | 200 | μF |
| Maximum Forward Voltage per Diode at $I_F = 1.0$ Amps. | V_F | 1.3 | | | | | Volts |
| Maximum Reverse Current at Rated Repetitive Peak Voltage per Diode | I_R | 10 | | | | | μA |
| Maximum Reverse Recovery Time (Note 1) | T_{rr} | 150 | | 250 | | 500 | ns |
| Typical Thermal Resistance (Note 2) | $R_{\theta JA}$ | 36 | | | | | $^\circ\text{C/W}$ |
| Operating Junction Temperature Range | T_J | - 50 to + 125 | | | | | $^\circ\text{C}$ |
| Storage Temperature Range | T_{STG} | - 50 to + 125 | | | | | $^\circ\text{C}$ |

Notes : 1) Measured with $I_F = 0.5$ Amp., $I_R = 1$ Amp., $I_{rr} = 0.25$ Amp.
 2) Thermal resistance from Junction to Ambient at 0.375" (9.5 mm) lead length P.C. Board with 0.22" x 0.22" (5.5 x 5.5 mm) copper Pads.

RATING AND CHARACTERISTIC CURVES (FB40 - FB380/C1000G)

**FIG.1 - DERATING CURVE
FOR OUTPUT RECTIFIED CURRENT
FB40 C1000G - FB125 C1000G**



**FIG.2 - DERATING CURVE
FOR OUTPUT RECTIFIED CURRENT
FB250 C1000G - FB380 C1000G**

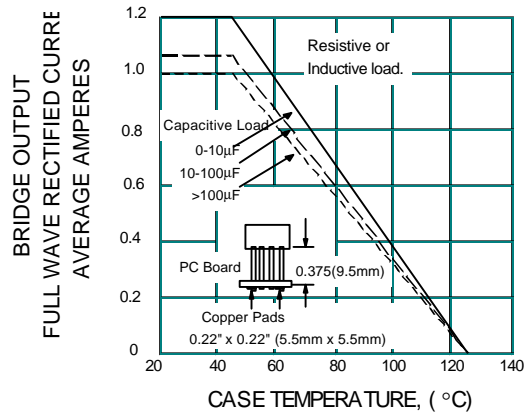


FIG.3 - TYPICAL FORWARD CHARACTERISTICS

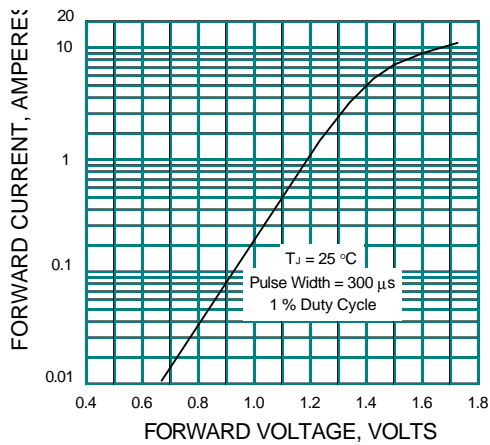


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

